ES3AF THRU ES3JF

Surface Mount Superfast Rectifiers

Reverse Voltage – 50 to 600 V

Forward Current – 3 A

FEATURES

- For surface mounted applications
- Low profile package
- Glass Passivated Chip Juntion
- Superfast reverse recovery time
- Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- Case: SMAF
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 27mg 0.00086oz

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Top View
Marking Code:
ES3AF~ES3JF: ES3A~ES3J
Simplified outline SMAF and symbol

Absolute Maximum Ratings and Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	ES3AF	ES3BF	ES3CF	ES3DF	ES3EF	ES3GF	ES3JF	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	600	V
Maximum RMS voltage	V_{RMS}	35	70	105	140	210	280	420	V
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	600	V
Maximum Average Forward Rectified Current at T_c = 125 °C	$I_{F(AV)}$	3							A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	I_{FSM}	80							A
Maximum Forward Voltage at 3 A	V_F	1				1.25		1.68	V
Maximum DC Reverse Current T_a = 25 °C at Rated DC Blocking Voltage T_a =125 °C	I_R	5 100							μA
Typical Junction Capacitance at V_R=4V, f=1MHz	C_j	40							pF
Maximum Reverse Recovery Time (1)	t_{rr}	35							ns
Typical Thermal Resistance (2)	$R_{\theta JA}$ $R_{\theta JC}$	50 16							°C/W
Operating and Storage Temperature Range	T_j, T_{stg}	-55 ~ +150							°C

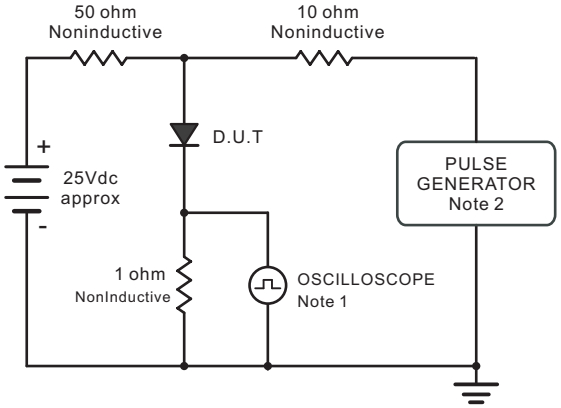
(1) Measured with I_F = 0.5 A, I_R = 1 A, I_{rr} = 0.25 A.

(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

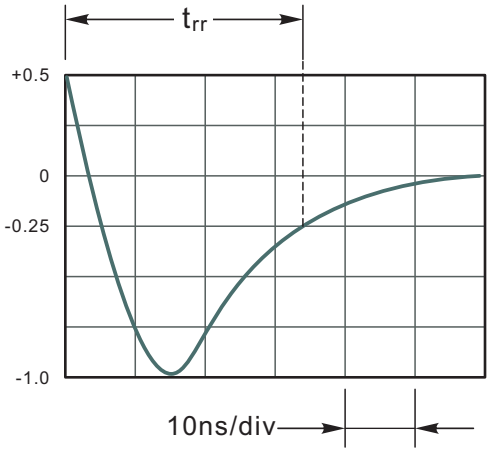
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Characteristic Curves (T_A=25 ℃ unless otherwise noted)

Fig.1 Reverse Recovery Time Characteristic And Test Circuit Diagram



Note: 1. Rise Time = 7ns, max.
Input Impedance = 1megohm,22pF.
2. Ries Time =10ns, max.
Source Impedance = 50 ohms.



Set time Base for 10ns/div

Fig.2 Maximum Average Forward Current Rating

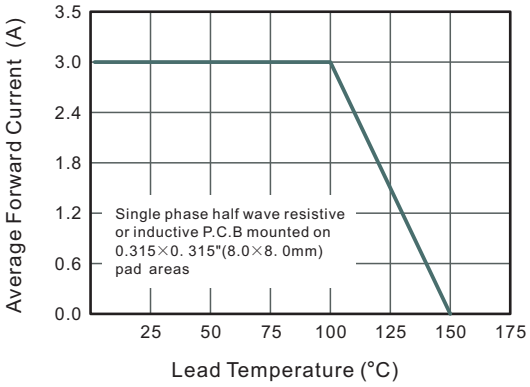


Fig.3 Typical Reverse Characteristics

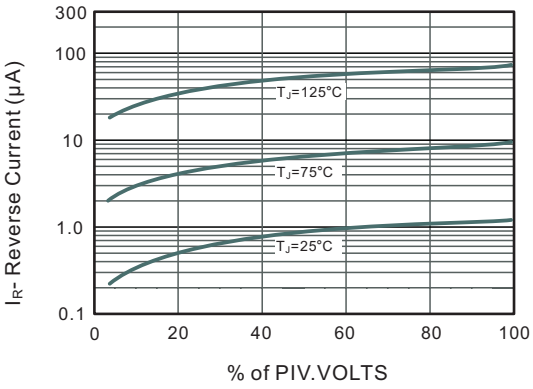


Fig.4 Typical Forward Characteristics

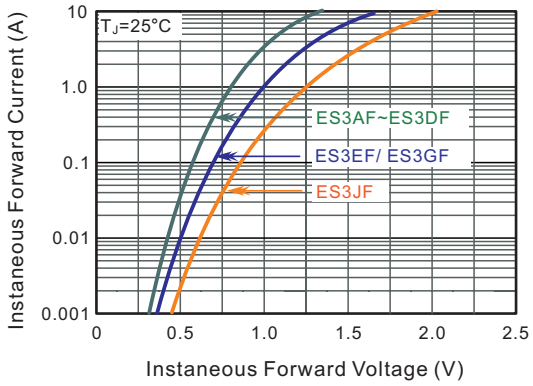
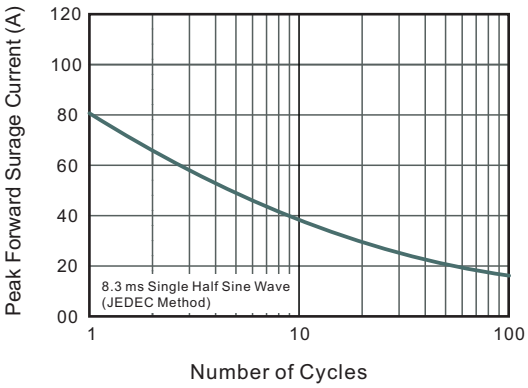


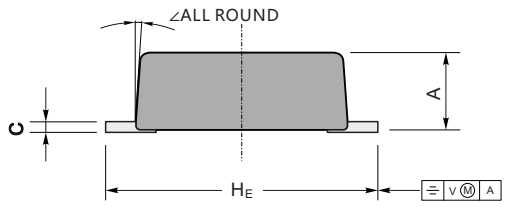
Fig.5 Typical Junction Capacitance

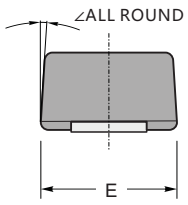


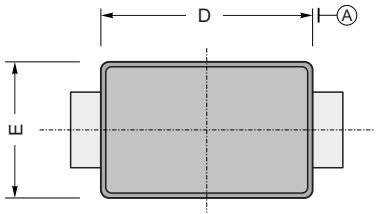
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PACKAGE OUTLINE

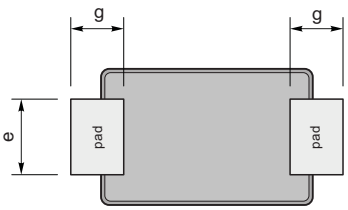
Plastic surface mounted package; 2 leads SMAF







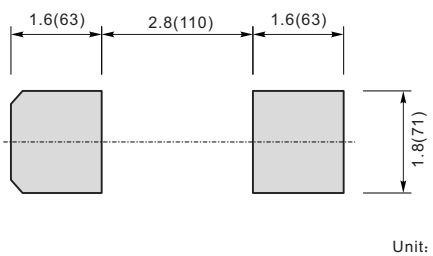
Top View



Bottom View

UNIT		A	C	D	E	e	g	H_E	∠
mm	max	1.2	0.23	3.7	2.7	1.6	1.3	4.9	7°
	min	0.9	0.18	3.3	2.4	1.3	1.0	4.4	
mil	max	47	9.1	146	106	63	51	193	
	min	35.4	7.1	130	94	51	39	173	

The recommended mounting pad size



Unit: mm(mil)

Marking

Type number	Marking code
ES3AF	ES3A
ES3BF	ES3B
ES3CF	ES3C
ES3DF	ES3D
ES3EF	ES3E
ES3GF	ES3G
ES3JF	ES3J

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